

## **Filterless High Efficiency 1.5W Class D Mono Amplifier**

The ISL99201 is a fully integrated high efficiency class-D mono amplifier. It is designed to maximize performance for mobile phone applications. The application circuit requires a minimum requirement of external components and operates from a 2.4V to 5.5V input supply. It is capable of delivering 1.4W of continuous output power with less than 1% THD+N driving a 8Ω load from a 5V supply.

The ISL99201 features a high-efficiency, low-noise modulation scheme. It operates with 86% efficiency at 400mW into 8Ω and has a signal-to-noise ratio (SNR) that is better than 95dB. The ISL99201 has a micro-power shutdown mode with a typical shutdown current of 200nA. Shutdown is enabled by applying a logic low to the SD pin.

The architecture of the devices allows it to achieve very low level of pop-and-click. This minimizes voltage glitches at the output during turn-on and turn-off, thus reducing audible noise on activation and deactivation.

The fully differential input of the ISL99201 provides excellent rejection of common mode noise on the input typically 75dB. EMI suppression is achieved by SRC (Slew Rate Control).

The ISL99201 oscillator can be synchronized to an external clock through the SYNC input, allowing the switching frequency to be externally defined. The SYNC input also allows multiple ISL99201 to be cascaded and frequency locked; minimizing interference due to clock intermodulation. SYNC is available only in DFN version.

The ISL99201 also has excellent rejection of power supply noise, including noise caused by GSM transmission bursts and RF rectification. PSRR is typically 75dB at 217Hz. There will be 4 versions of the part; they will consist of three fixed gain settings (6dB, 9.6dB, 12dB) and one user programmable gain setting (need external resistors).

The ISL99201 has built-in thermal shutdown and output short-circuit protection.

## **Features**

- Filterless Class D with Efficiency > 86% at 400mW
- Click-Pop Suppression
- Slew Rate Control
- Spread Spectrum Switching
- Optional SYNC Pin for Master/Slave Operation Without Interface (Only in TDFN)
- 1.4W into 8Ω with Less than 1% THD+N
- 2.4V to 5.5V Single Supply Voltage
- Built-in Resistors to Reduce Board Component Count
- Only One External Component Required (Fixed Gain Mode)
- Short Circuit and Thermal Protection
- Gain Programmable 6dB, 9.6dB, 12dB and User Programmable
- Pb-Free (RoHS compliant)

## **Applications**

- Mobile Phones
- MP3 Players
- Portable Gaming
- Portable Electronics
- Educational Toys

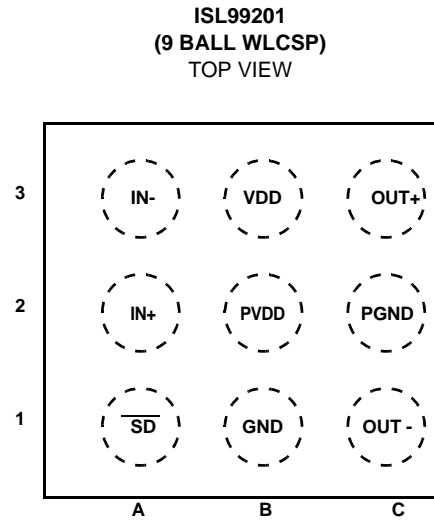
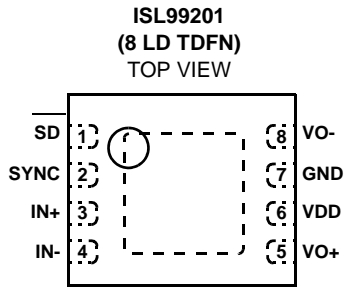
## Ordering Information

PART NUMBER	PART MARKING	GAIN SETTING (dB)	TEMP. RANGE (°C)	PACKAGE Tape & Reel (Pb-Free)	PKG. DWG. #
ISL99201IRTAZ-T (Notes 1, 2)	201A	6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTAZ-TK (Notes 1, 2)	201A	6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTBZ-T (Notes 1, 2)	201B	9.6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTBZ-TK (Notes 1, 2)	201B	9.6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTCZ-T (Notes 1, 2)	201C	12	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTCZ-TK (Notes 1, 2)	201C	12	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTDZ-T (Notes 1, 2)	201D	Prog.	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTDZ-TK (Notes 1, 2)	201D	Prog.	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IIAZ-T (Notes 1, 3, 4)	201A	6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIAZ-TK (Notes 1, 3, 4)	201A	6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIBZ-T (Notes 1, 3, 4)	201B	9.6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIBZ-TK (Notes 1, 3, 4)	201B	9.6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IICZ-T (Notes 1, 3, 4)	201C	12	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IICZ-TK (Notes 1, 3, 4)	201C	12	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIDZ-T (Notes 1, 3, 4)	201D	Prog.	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIDZ-TK (Notes 1, 3, 4)	201D	Prog.	-40 to +85	9 Ball WLCSP	W3x3.9C

### NOTES:

1. Please refer to TB347 for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. These Intersil Pb-free WLCSP and BGA packaged products employ special Pb-free material sets; molding compounds/die attach materials and SnAgCu - e1 solder ball terminals, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free WLCSP and BGA packaged products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
4. Please contact factory for ordering details.

**Pinouts**



**Absolute Maximum Ratings (Reference to GND)**

Supply Voltage ..... -0.3V to 6V  
 Input Voltage ..... -0.3V to V<sub>DD</sub>+0.3V

**Recommended Operating Conditions**

Ambient Temperature Range ..... -40°C to +85°C  
 Operating Supply Voltage (V<sub>DD</sub> Pin) ..... 2.4V to 5.5V

**Thermal Information**

Thermal Resistance (Typical Note 5)  $\theta_{JA}$  (°C/W)  
 WLCSP Package ..... 102  
 TDFN Package ..... 53  
 Maximum Junction Temperature (Plastic Package) -65°C to +150°C  
 Maximum Storage Temperature Range ..... -65°C to +150°C  
**Power Dissipation Ratings**  
 8 Ld 3x3 TDFN  
 Derating Factor ..... 21.8mW/°C  
**Power Ratings**  
 T<sub>A</sub> = +25°C ..... 2.7W  
 T<sub>A</sub> = +70°C ..... 1.7W  
 T<sub>A</sub> = +85°C ..... 1.4W  
 9 Ball WLCSP  
 Derating Factor ..... 7.5mW/°C  
**Power Ratings**  
 T<sub>A</sub> = +25°C ..... 1.01W  
 T<sub>A</sub> = +70°C ..... 0.67W  
 T<sub>A</sub> = +85°C ..... 0.56W  
 Pb-Free Reflow Profile ..... see link below  
<http://www.intersil.com/pbfree/Pb-FreeReflow.asp>

*CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.*

**NOTE:**

- 5.  $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with “direct attach” features. See Tech Brief TB379.

**Electrical Specifications**

Typical Values Are Tested at V<sub>DD</sub> = 5V and the Ambient Temperature at +25°C. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Power	P <sub>O</sub>	R <sub>L</sub> = 8Ω, THD = 10%, f = 1kHz, 20kHz BW, V <sub>DD</sub> = 5.0V		1.4		W
		R <sub>L</sub> = 8Ω, THD = 10%, f = 1kHz, 20kHz BW, V <sub>DD</sub> = 3.6V		0.75		W
		R <sub>L</sub> = 8Ω, THD = 10%, f = 1kHz, 20kHz BW, V <sub>DD</sub> = 2.5V		0.4		W
		R <sub>L</sub> = 8Ω, THD = 1%, f = 1kHz, 20kHz BW, V <sub>DD</sub> = 5.0V		1.15		W
Efficiency	$\eta$	P <sub>OUT</sub> = 1.4W, 8Ω + 33μH, V <sub>DD</sub> = 5.0V		90		%
Total Harmonic Distortion + Ratio	THD+N	P <sub>O</sub> = 1W into 8Ω each channel, f = 1kHz, V <sub>DD</sub> = 5.0V		0.05		%
		P <sub>O</sub> = 0.5W into 8Ω each channel, f = 1kHz, V <sub>DD</sub> = 3.6V		0.05		%
		P <sub>O</sub> = 0.2W into 8Ω each channel, f = 1kHz, V <sub>DD</sub> = 3.6V		0.09		%
Common-Mode Rejection Ratio	CMRR	V <sub>IC</sub> = 0.5V to (V <sub>DD</sub> - 0.8V); R <sub>L</sub> = 8Ω, V <sub>DD</sub> = 2.5V to 5.5V		-60		dB
	CMRR <sub>GSM</sub>	V <sub>CM</sub> = 2.5V ± 1V <sub>P-P</sub> at 217Hz, R <sub>L</sub> = 8Ω		-60		dB
Average Switching Frequency	f <sub>sw</sub>	V <sub>DD</sub> = 5V	300	375	450	kHz
Differential Output Offset Voltage	V <sub>OOS</sub>	G = 6dB; 9.6dB; 12dB; 28dB.		0.2	5.0	mV
<b>POWER SUPPLY</b>						
Supply Voltage Range	V <sub>DD</sub>		2.4		5.5	V
Power Supply Rejection Ratio	PSRR	V <sub>DD</sub> = 2.5V to 5.0V		-65		dB
	PSRR <sub>GSM</sub>	V <sub>RIPPLT</sub> = 100mV <sub>RMS</sub> at 217Hz (Input AC-Coupled with 2μF capacitor)		-65		dB

**Electrical Specifications** Typical Values Are Tested at  $V_{DD} = 5V$  and the Ambient Temperature at  $+25^{\circ}C$ . Parameters with MIN and/or MAX limits are 100% tested at  $+25^{\circ}C$ , unless otherwise specified. Temperature limits established by characterization and are not production tested. **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Supply Current	$I_{IN}$	$V_{IN} = 0V$ , No load, $V_{DD} = 5V$		3.9		mA
		$V_{IN} = 0V$ , No load, $V_{DD} = 3.6V$		3.2	3.75	mA
		$V_{IN} = 0V$ , $8\Omega + 33\mu H$ , $V_{DD} = 5V$		3.9		mA
		$V_{IN} = 0V$ , $8\Omega + 33\mu H$ , $V_{DD} = 3.6V$		3.8		mA
	$\overline{SD}$ (Note 6)	$\overline{SD} = GND$		0.2	0.4	$\mu A$
<b>GAIN CONTROL</b>						
Closed-Loop Gain		D version user program ( Max Gain, $R_i = 0\Omega$ )	27.5	28.5	29.5	dB
		A version	5.7	6	6.3	dB
		B version	9.2	9.6	10	dB
		C version	11.5	12	12.5	dB
Differential Input Impedance	$Z_{IN}$	$\overline{SD} = V_{DD}$ , A version		70		$k\Omega$
		$\overline{SD} = V_{DD}$ , B version		46.25		$k\Omega$
		$\overline{SD} = V_{DD}$ , C version		35		$k\Omega$
		$\overline{SD} = V_{DD}$ , D version, $R_i = 2.5k\Omega$		7.5		$k\Omega$
		$\overline{SD} = GND$		100		$k\Omega$
<b>SHUTDOWN CONTROL</b>						
Input Voltage High	$V_{IH}$			1.2		V
Input Voltage Low	$V_{IL}$			0.5		V
Turn-on Time	$t_{WU}$	$\overline{SD}$ rising edge from GND to $V_{DD}$		3.5		ms
Turn-off Time	$t_{SD}$	$\overline{SD}$ falling edge from $V_{DD}$ to GND		5		$\mu s$
Output Impedance	$Z_{OUT}$	$\overline{SD} = GND$		>100		$k\Omega$
<b>NOISE PERFORMANCE</b>						
Output Voltage Noise	$E_n$	$V_{DD} = 3.6V$ , $f = 20Hz$ to $20kHz$ , inputs are AC grounded, $A_V = 6dB$ , A-weighting		27		$\mu V$
		$V_{DD} = 3.6V$ , $f = 20Hz$ to $20kHz$ , inputs are AC grounded, $A_{V0} = 6dB$ , no weighting		35		$\mu V$
Signal-to-Noise Ratio	SNR	$P_{OUT} = 1W$ , $R_L = 8\Omega$		102		dB

NOTE:

- Limits established by Characterization and are not production tested

**Pin Descriptions**

**$\overline{SD}$**

Shutdown Active Low. This signal is used to shut down and activate the part. It is 1.8V to 5V compatible. During shutdown, the part draws less than 100nA input current. Coming out of shutdown takes 3.5ms and going into shutdown is instantaneous.

**SYNC**

External clock input (available only in DFN). This pin allows the chip to be synchronized to a system clock. This helps in folding the spectral components and the switching harmonic out of band of interest. The range of SYNC frequency is from 250kHz to 800kHz.

**IN+**

Positive Differential Input.

**IN-**

Negative Differential Input.

**VO+**

Positive BTL output.

**GND**

Ground (Analog ground in CSP)

**VDD**

Power Supply (Analog VDD in CSP)

**VO-**

Negative BTL output

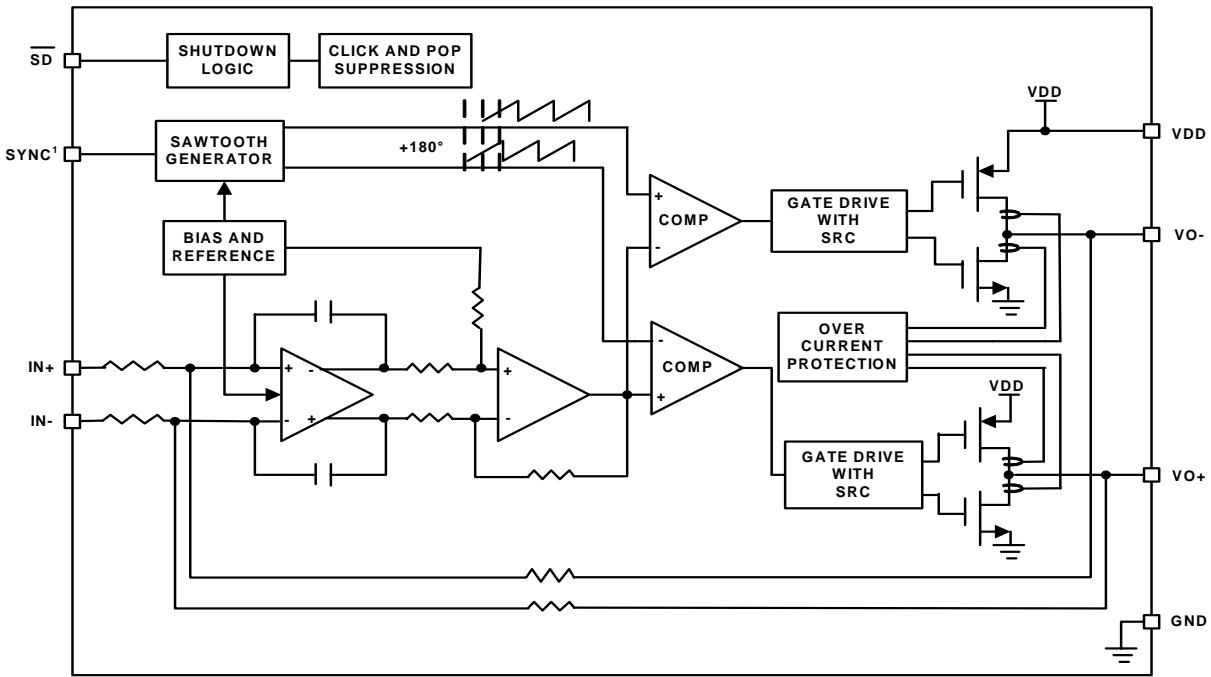
**PVDD**

Power Supply (CSP only)

**PGND**

Power Ground (CSP only)

**Block Diagram (Notes \*)**



Notes:

Gain = 6dB, 9.6dB, 12dB (gain setting)

$$\text{Gain} = \frac{140\text{k}\Omega}{(R_i + 5\text{k}\Omega)} ; \text{ with external resistor}$$

\*TDFN only

Typical Performance Characteristics

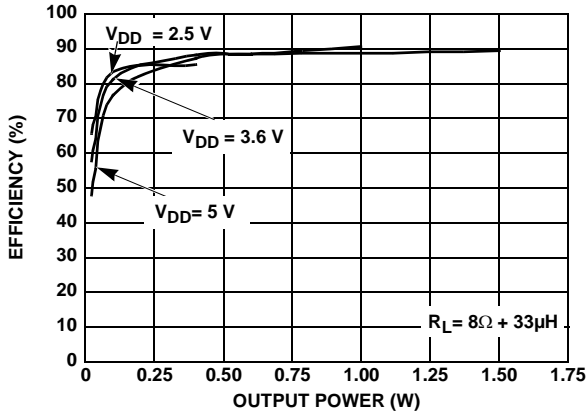


FIGURE 1. EFFICIENCY vs OUTPUT POWER

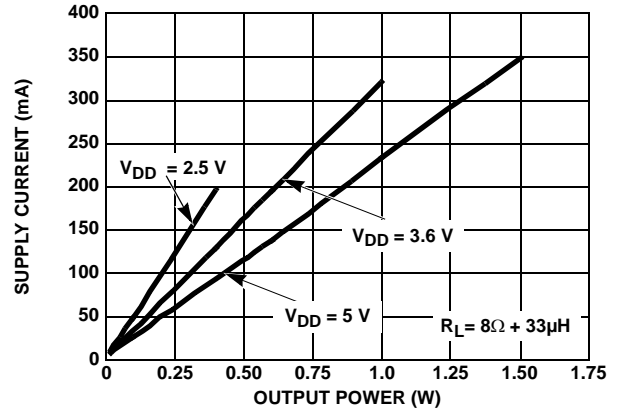


FIGURE 2. SUPPLY CURRENT vs OUTPUT POWER

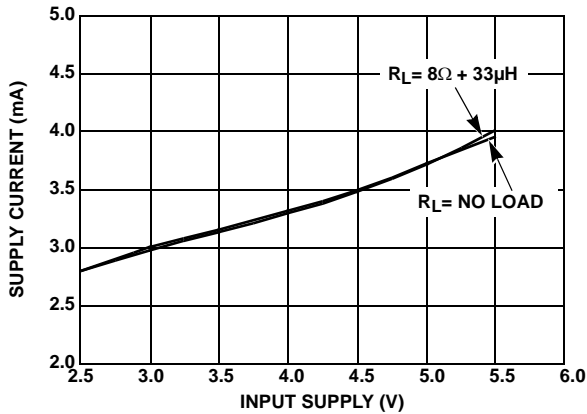


FIGURE 3. SUPPLY CURRENT vs SUPPLY VOLTAGE

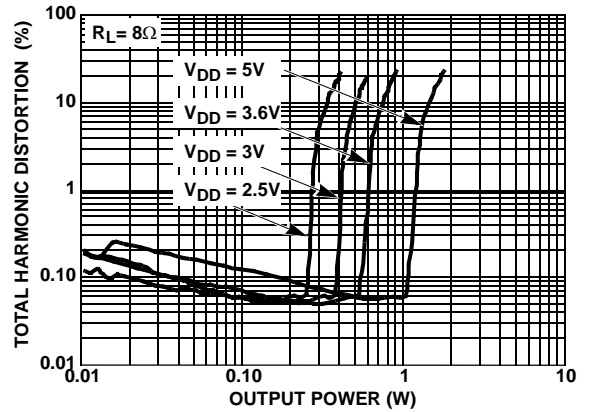


FIGURE 4. TOTAL HARMONIC DISTORTION + NOISE vs OUTPUT POWER

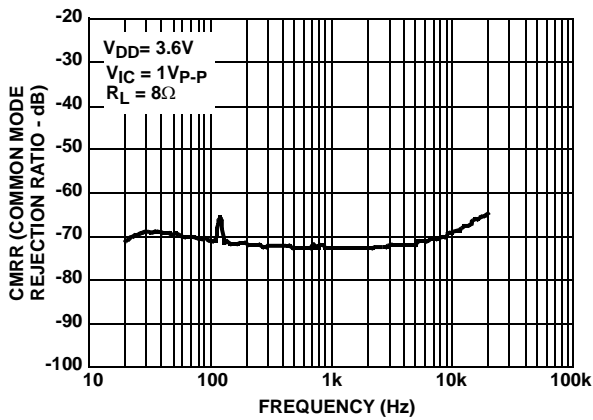


FIGURE 5. COMMON MODE REJECTION MODE vs FREQUENCY

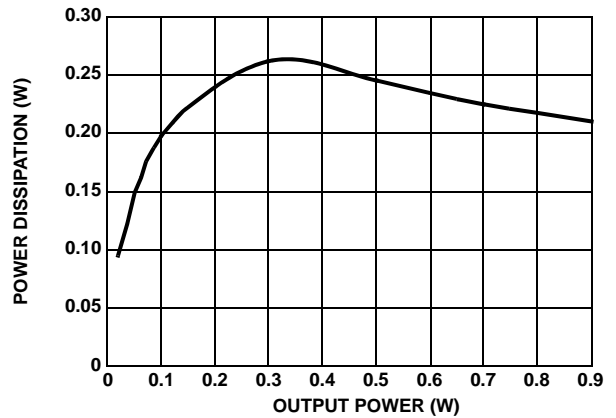


FIGURE 6. POWER DISSIPATION vs OUTPUT POWER

Typical Performance Characteristics (Continued)

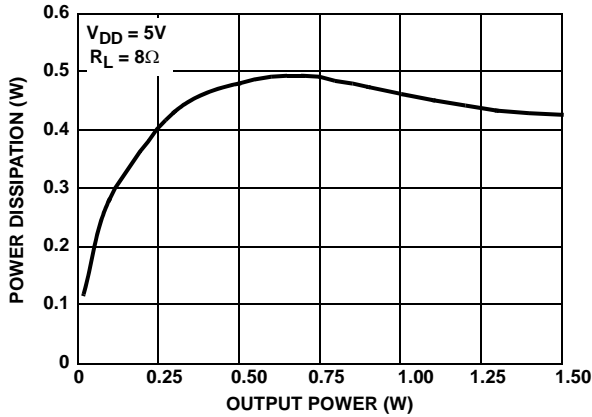


FIGURE 7. POWER DISSIPATION vs OUTPUT POWER

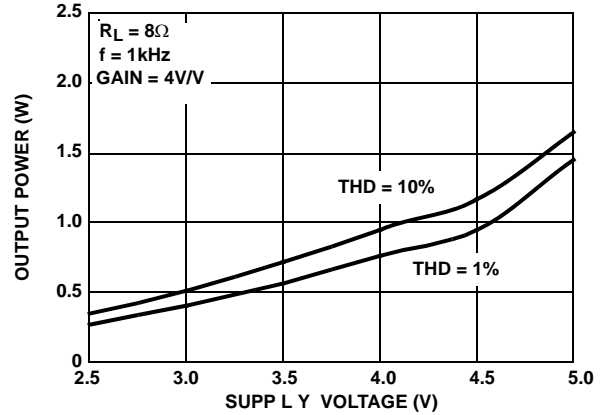


FIGURE 8. OUTPUT POWER vs SUPPLY VOLTAGE

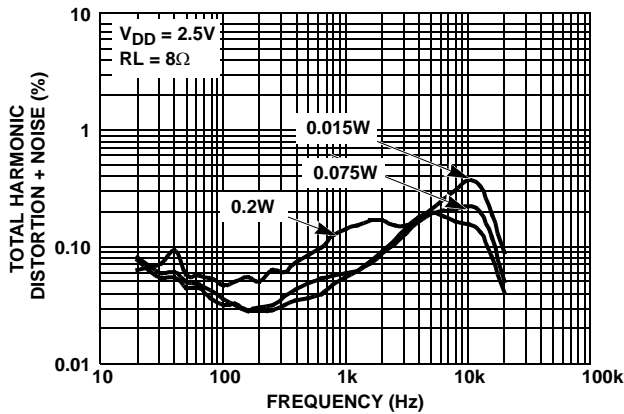


FIGURE 9. TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

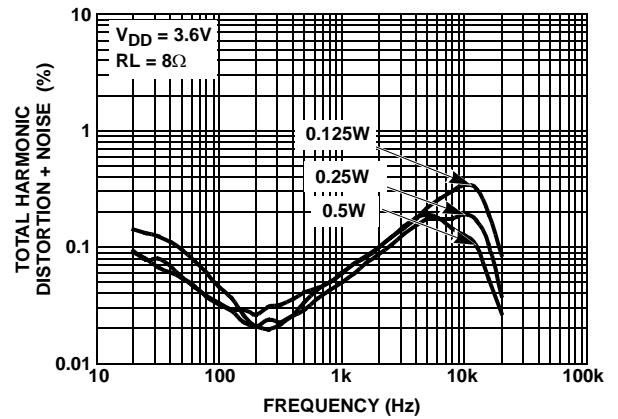


FIGURE 10. TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

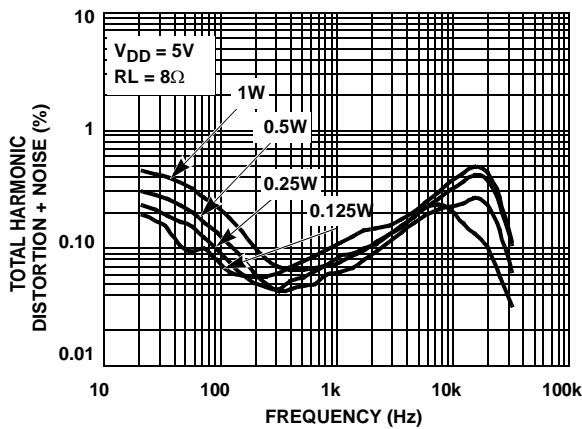


FIGURE 11. TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

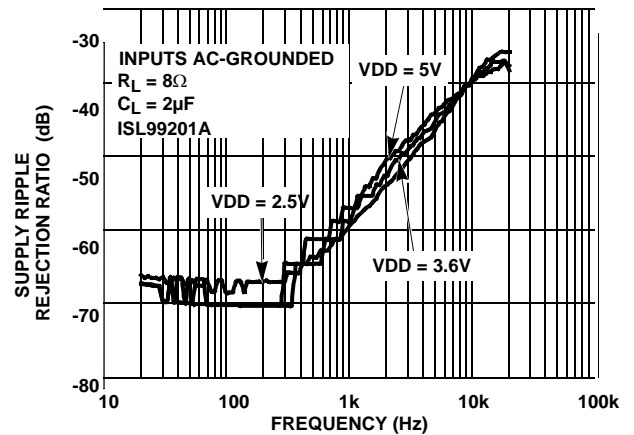


FIGURE 12. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201A



Typical Performance Characteristics (Continued)

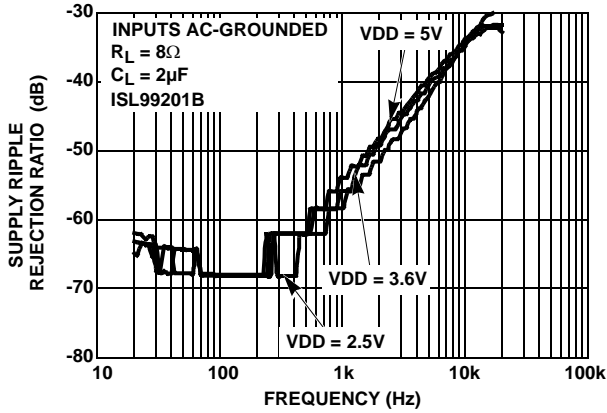


FIGURE 13. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201B

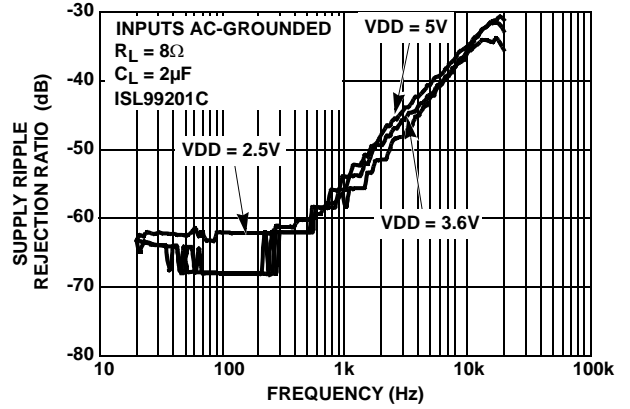


FIGURE 14. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201C

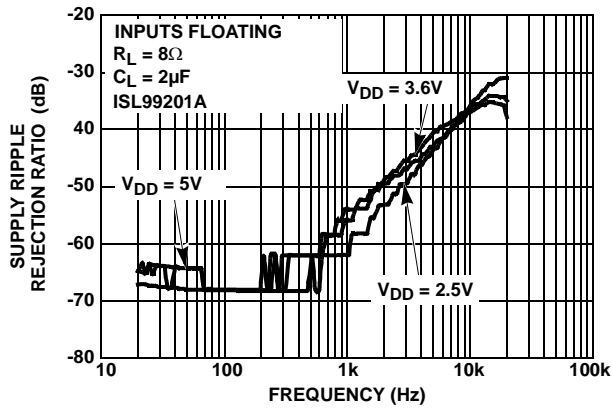


FIGURE 15. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201A

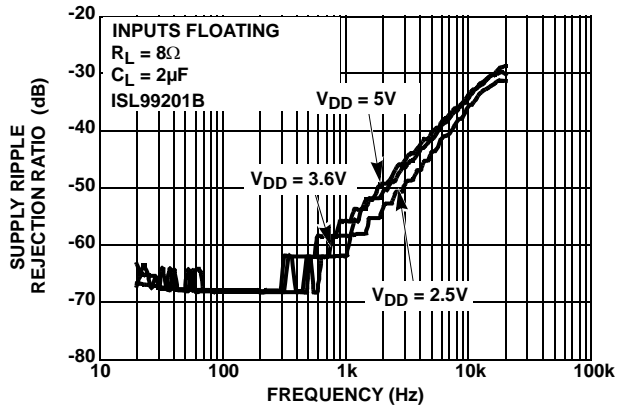


FIGURE 16. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201B

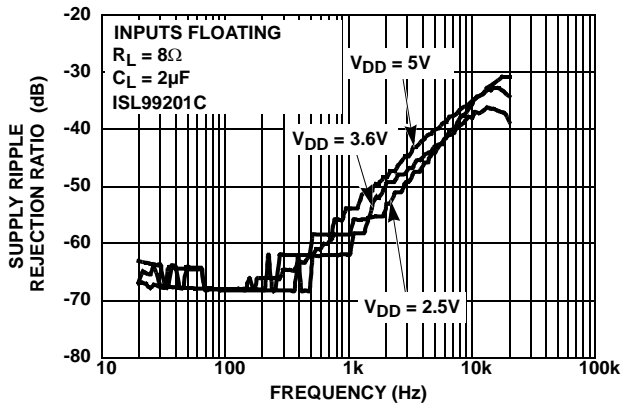


FIGURE 17. SUPPLY RIPPLE REJECTION RATIO vs FREQUENCY - ISL99201C

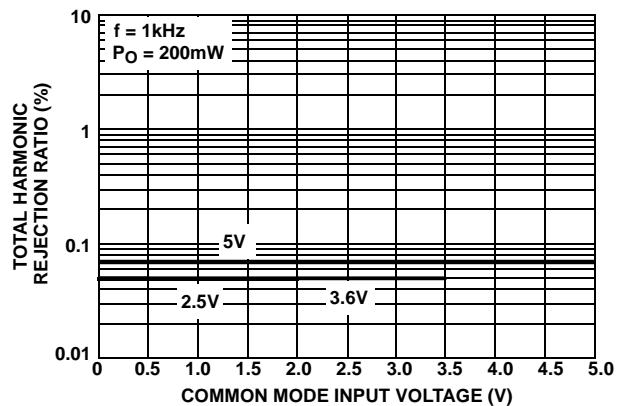


FIGURE 18. TOTAL HARMONIC DISTORTION + NOISE vs COMMON MODE INPUT VOLTAGE

Typical Performance Characteristics (Continued)

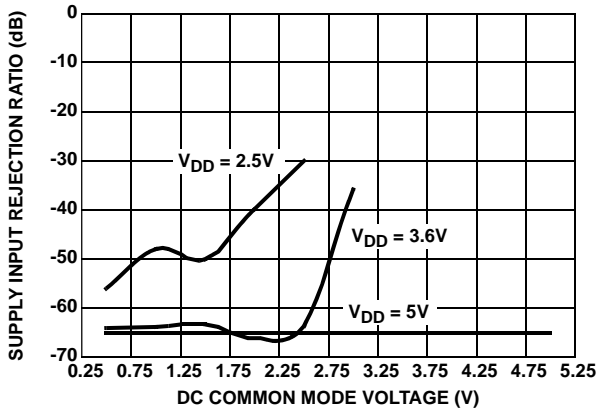


FIGURE 19. SUPPLY RIPPLE REJECTION RATIO vs DC COMMON MODE VOLTAGE

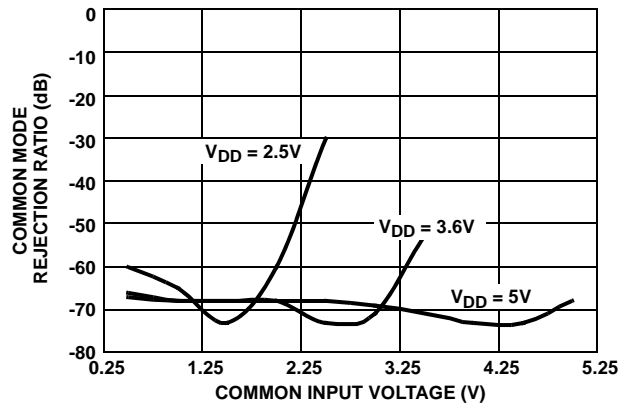


FIGURE 20. COMMON MODE REJECTION RATIO vs COMMON MODE INPUT VOLTAGE

Typical Applications

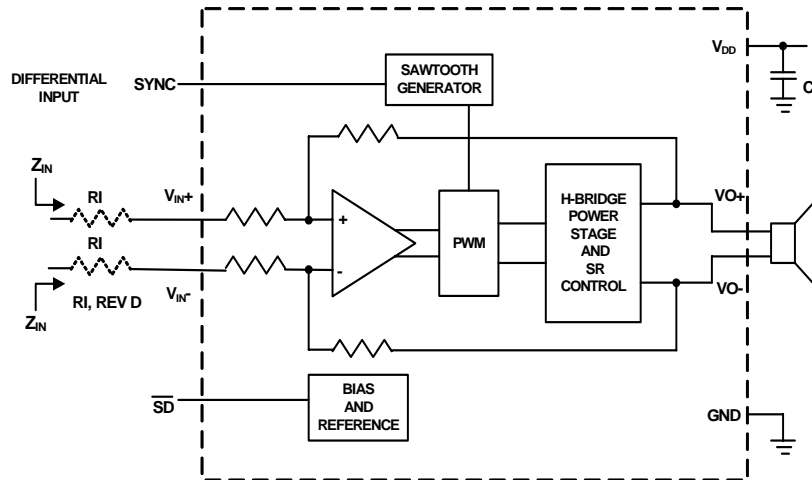


FIGURE 21. TYPICAL CIRCUIT WITH DIFFERENTIAL INPUT

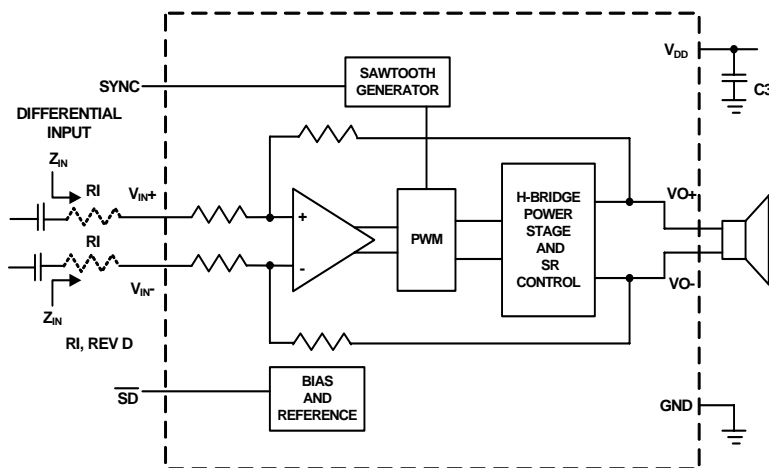


FIGURE 22. TYPICAL CIRCUIT WITH DIFFERENTIAL INPUT AND INPUT CAPACITORS

Typical Applications (Continued)

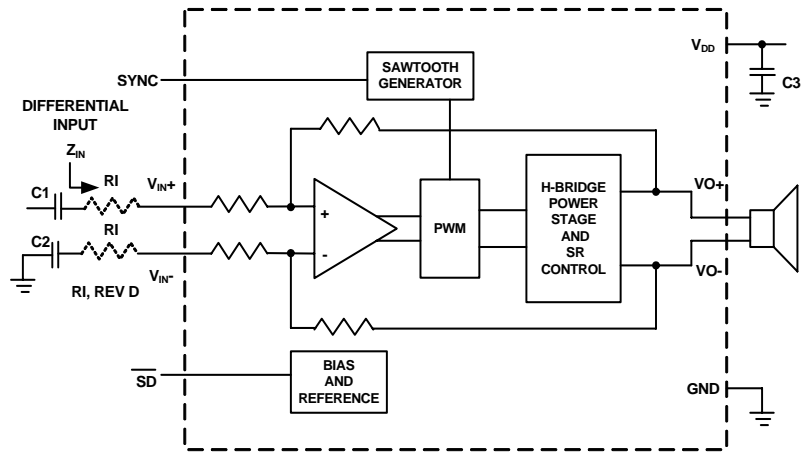
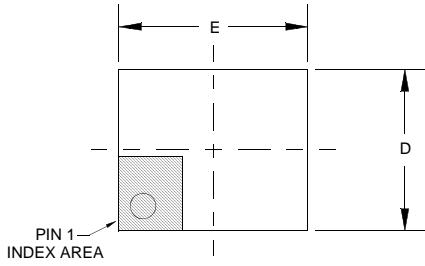
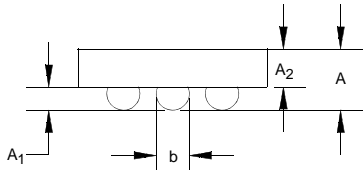


FIGURE 23. TYPICAL CIRCUIT WITH SINGLE-ENDED INPUT

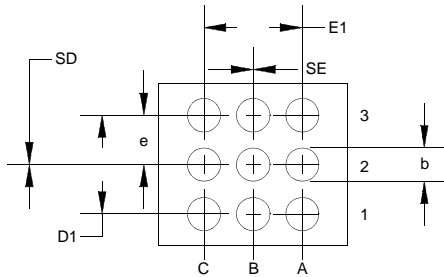
**Wafer Level Chip Scale Package  
(WLCSP 0.4mm Ball Pitch)**



TOP VIEW



SIDE VIEW



BOTTOM VIEW

**W3x3.9C**

3x3 ARRAY 9 BALL WAFER LEVEL CHIP SCALE PACKAGE

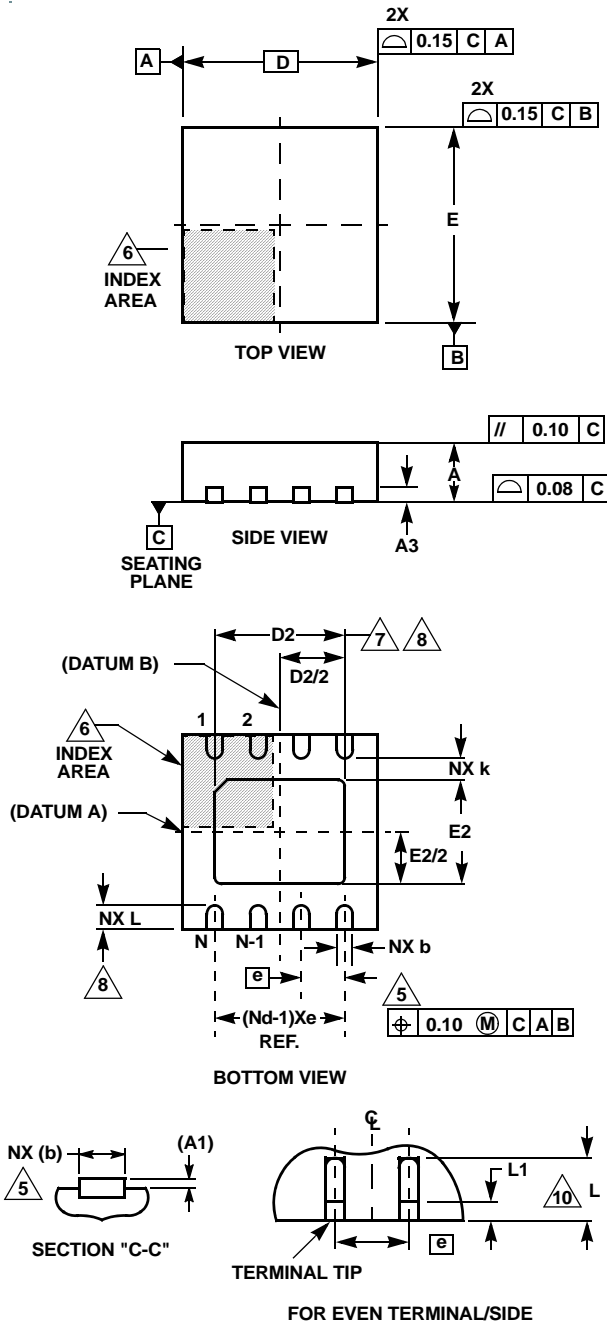
SYMBOL	MILLIMETERS
A	0.445 Min, 0.495 Nom, 0.545 Max
A <sub>1</sub>	0.190 ±0.025
A <sub>2</sub>	0.305 ±0.025
b	0.270 ±0.030
D	1.315 ±0.020
D <sub>1</sub>	0.800 BASIC
E	1.535 ±0.020
E <sub>1</sub>	0.800 BASIC
e	0.400 BASIC
SD	0 BASIC
SE	0 BASIC
Number of Bumps: 9	

Rev. 0 5/08

NOTES:

1. Dimensions are in Millimeters.

**Thin Dual Flat No-Lead Plastic Package (TDFN)**  
Dual Flat No - Lead Plastic package (DFN)



**L8.3x3A**  
8 LEAD THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE

SYMBOL	MILLIMETERS			NOTES
	MIN	NOMINAL	MAX	
A	0.70	0.75	0.80	-
A1	-	0.02	0.05	-
A3	0.20 REF			-
b	0.25	0.30	0.35	5, 8
D	3.00 BSC			-
D2	2.20	2.30	2.40	7, 8, 9
E	3.00 BSC			-
E2	1.40	1.50	1.60	7, 8, 9
e	0.65 BSC			-
k	0.25	-	-	-
L	0.20	0.30	0.40	8
N	8			2
Nd	4			3

Rev. 3 11/04

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
2. N is the number of terminals.
3. Nd refers to the number of terminals on D.
4. All dimensions are in millimeters. Angles are in degrees.
5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.
8. Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.
9. Compliant to JEDEC MO-WEEC-2 except for the "L" min dimension.

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